

# Photointerrupter, double-layer mold type

## RPI-221

The RPI-221 is an ultra-small size, double-layer mold photointerrupter.

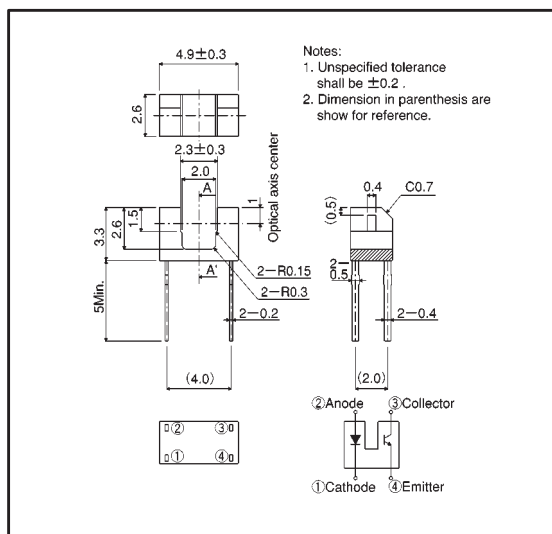
### ●Applications

Optical control equipment  
Cameras  
Floppy disk drives

### ●Features

- 1) Ultra-small.
- 2) Minimal influence from stray light.
- 3) Low collector-emitter saturation voltage.

### ●External dimensions (Units: mm)



### ●Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Input(LED)	Forward current	$I_F$	50	mA
	Reverse voltage	$V_R$	5	V
	Power dissipation	$P_D$	80	mW
Output (photo-transistor)	Collector-emitter voltage	$V_{CEO}$	30	V
	Emitter-collector voltage	$V_{ECO}$	4.5	V
	Collector current	$I_C$	30	mA
	Collector power dissipation	$P_C$	80	mW
Operating temperature		$T_{opr}$	-25 ~ +85	°C
Storage temperature		$T_{stg}$	-30 ~ +85	°C

●Electrical and optical characteristics (Ta = 25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Input characteristics	Forward voltage	$V_F$	—	1.3	1.6	V	$I_F=50\text{mA}$
	Reverse current	$I_R$	—	—	10	$\mu\text{A}$	$V_R=5\text{V}$
Output characteristics	Dark current	$I_{CEO}$	—	—	0.5	$\mu\text{A}$	$V_{CE}=10\text{V}$
	Peak sensitivity wavelength	$\lambda_P$	—	800	—	nm	—
Transfer characteristics	Collector current	$I_C$	0.2	1.0	—	mA	$V_{CE}=5\text{V}, I_F=20\text{mA}$
	Collector-emitter saturation voltage	$V_{CE(sat)}$	—	—	0.4	V	$I_F=20\text{mA}, I_C=0.1\text{mA}$
	Response time	$t_r \cdot t_f$	—	10	—	$\mu\text{s}$	$V_{CC}=5\text{V}, I_F=20\text{mA}, R_L=100\Omega$

●Electrical and optical characteristic curves

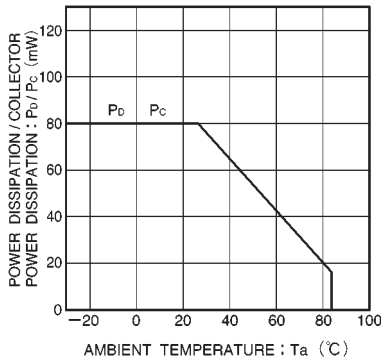


Fig.1 Power dissipation / collector power dissipation vs. ambient temperature

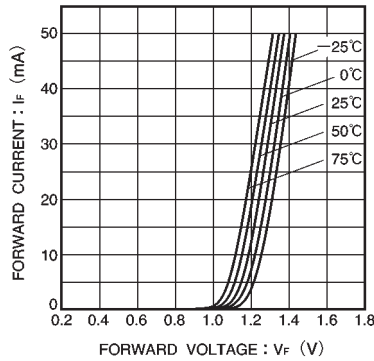


Fig.2 Forward current vs. forward voltage

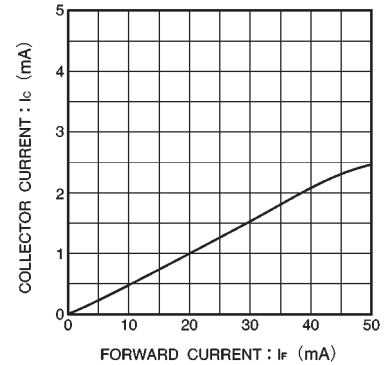


Fig.3 Collector current vs. forward current

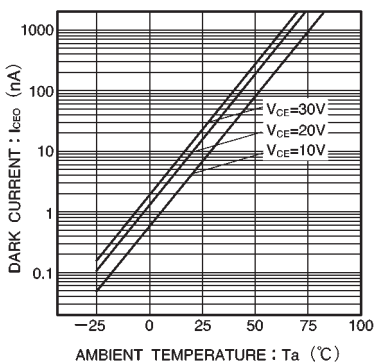


Fig.4 Dark current vs. ambient temperature

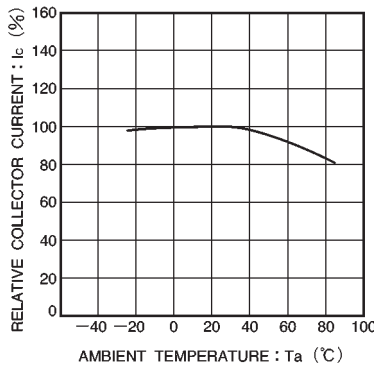


Fig.5 Relative output vs. ambient temperature

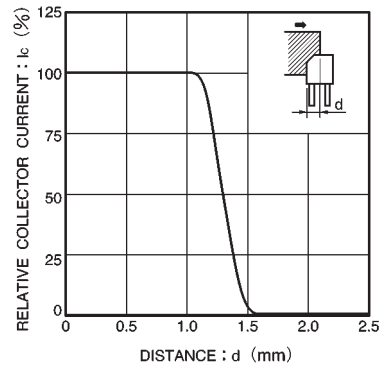


Fig.6 Relative output vs. distance (I)

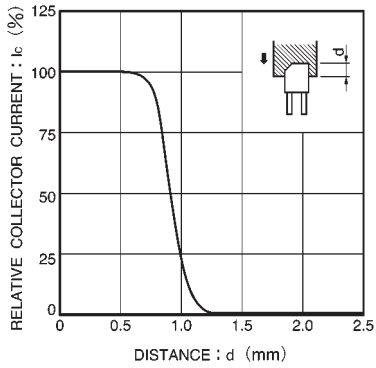


Fig.7 Relative output vs. distance (II)

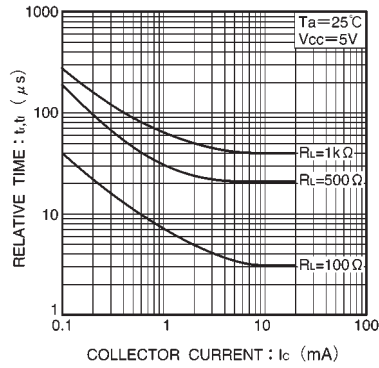


Fig.8 Response time vs. output current

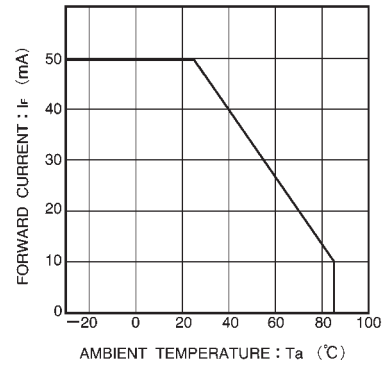


Fig.9 Forward current falloff

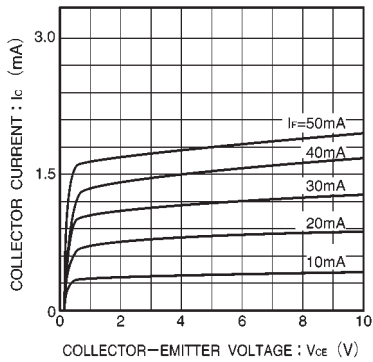


Fig.10 Output characteristics

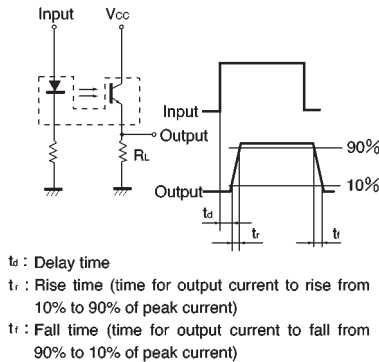


Fig.11 Response time measurement circuit